

MOS INTEGRATED CIRCUIT $\mu PD23C64000JL$

64M-BIT MASK-PROGRAMMABLE ROM 8M-WORD BY 8-BIT (BYTE MODE) / 4M-WORD BY 16-BIT (WORD MODE)

Description

The μ PD23C64000JL is a 67,108,864 bits mask-programmable ROM. The word organization is selectable (BYTE mode : 8,388,608 words by 8 bits, WORD mode : 4,194,304 words by 16 bits).

The active levels of OE (Output Enable Input) can be selected with mask-option.

The μ PD23C64000JL is packed in 48-pin PLASTIC TSOP (I) and 44-pin PLASTIC SOP.

Features

Word organization

8,388,608 words by 8 bits (BYTE mode)

4,194,304 words by 16 bits (WORD mode)

• Operating supply voltage: Vcc = 2.7 to 3.6 V

Operating	Package	Access time	Power supply current	Standby current
supply voltage		ns (MAX.)	(Active mode)	(CMOS level input)
Vcc			mA (MAX.)	μA (MAX.)
3.0 V ± 0.3 V	TSOP (I)	100	40	30
	SOP	120	35	
3.3 V ± 0.3 V	TSOP (I)	90	55	
	SOP	100	50	

Remark The access time and power supply current vary depending on the package type.

Ordering Information

Part number	Package
μPD23C64000JLGY-xxx-MJH	48-pin PLASTIC TSOP (I) (12 × 18) (Normal bent)
μ PD23C64000JLGY-xxx-MKH	48-pin PLASTIC TSOP (I) (12 \times 18) (Reverse bent)
μ PD23C64000JLGX-xxx	44-pin PLASTIC SOP (15.24 mm (600))

(xxx: ROM code suffix No.)

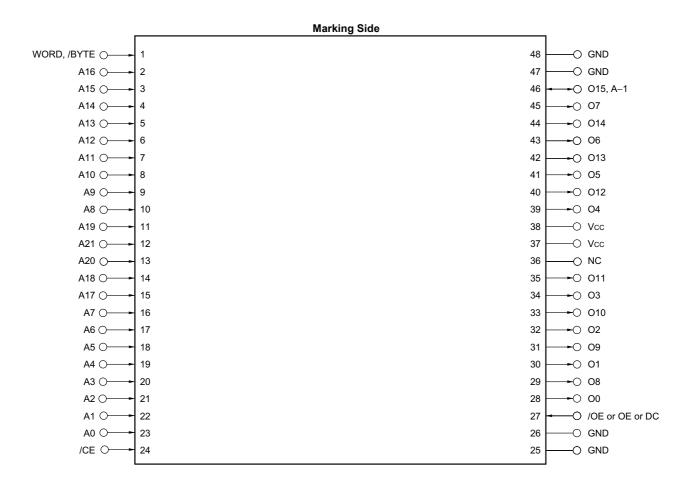
The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

Pin Configurations

/xxx indicates active low signal.

48-pin PLASTIC TSOP (I) (12 \times 18) (Normal bent) [μ PD23C64000JLGY-xxx-MJH]



A0 to A21 : Address inputs
O0 to O7, O8 to O14 : Data outputs

O15, A-1 : Data output 15 (WORD mode),

LSB Address input (BYTE mode)

WORD, /BYTE : Mode select
/CE : Chip Enable
/OE or OE : Output Enable
Vcc : Supply voltage

GND : Ground

NC No Connection
DC : No Connection

Note Some signals can be applied because this pin is not connected to the inside of the chip.

Remark Refer to Package Drawings for the 1-pin index mark.

48-pin PLASTIC TSOP (I) (12 \times 18) (Reverse bent) [μ PD23C64000JLGY-xxx-MKH]

	Marking Side		
GND ○	48 1		WORD, /BYTE
GND O-	47 2		A16
O15, A−1 ⊖ 	46 3		A15
07 🔾	45 4		A14
O14 O-	44 5		A13
06 ○-	43 6		A12
O13 O 	42 7		A11
O5 O -	41 8		A10
O12 O-	40 9		A9
O4 O -	39 10	•	A8
Vcc	38 11		A19
Vcc	37 12		A21
NC ()	36 13		A20
011 ○-	35 14		A18
O3 ()-	34 15		A17
O10 ○ -	33 16		A7
02 ○-	32 17		A6
09 ○-	31 18	-	A5
01 🔾 🗕	30 19	•	A4
08 ○-	29 20		A3
O0 O -	28 21		A2
/OE or OE or DC O	27 22	-	A1
GND ○	26 23		A0
GND ○	25 24		/CE

A0 to A21 : Address inputs O0 to O7, O8 to O14 : Data outputs

O15, A-1 : Data Output 15 (WORD mode),

LSB Address input (BYTE mode)

WORD, /BYTE : Mode select
/CE : Chip Enable
/OE or OE : Output Enable
Vcc : Supply voltage

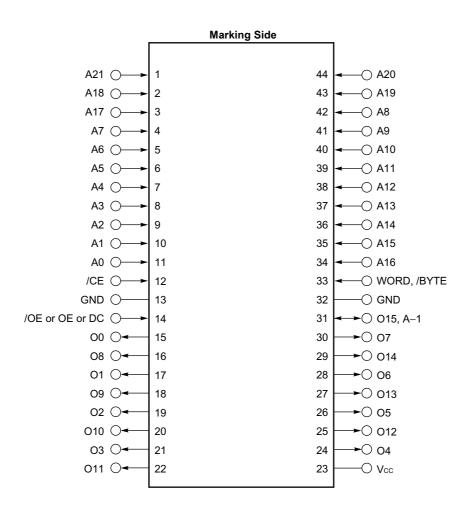
GND : Ground

NC No Connection
DC : No Connection

Note Some signals can be applied because this pin is not connected to the inside of the chip.

Remark Refer to Package Drawings for the 1-pin index mark.

44-pin PLASTIC SOP (15.24 mm (600)) [μ PD23C64000JLGX-xxx]



A0 to A21 : Address inputs
O0 to O7, O8 to O14 : Data outputs

O15, A-1 : Data Output 15 (WORD mode),

LSB Address input (BYTE mode)

WORD, /BYTE : Mode select
/CE : Chip Enable
/OE or OE : Output Enable
Vcc : Supply voltage
GND : Ground
DC : Don't Care

Remark Refer to Package Drawings for the 1-pin index mark.

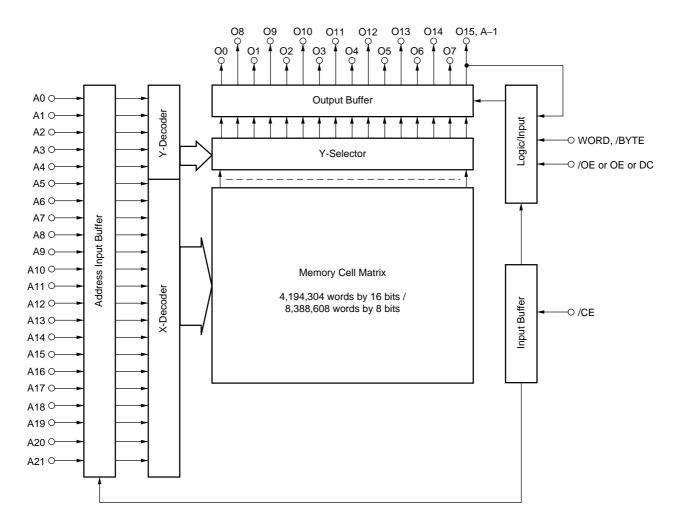


Input / Output Pin Functions

Pin name	Input / Output	Function
WORD, /BYTE	Input	The pin for switching WORD mode and BYTE mode.
		High level: WORD mode (4M-word by 16-bit)
		Low level : BYTE mode (8M-word by 8-bit)
A0 to A21	Input	Address input pins.
(Address inputs)		A0 to A21 are used differently in the WORD mode and the BYTE mode.
		WORD mode (4M-word by 16-bit)
		A0 to A21 are used as 22 bits address signals.
		BYTE mode (8M-word by 8-bit)
		A0 to A21 are used as the upper 22 bits of total 23 bits of address signal.
		(The least significant bit (A-1) is combined to O15.)
O0 to O7, O8 to O14	Output	Data output pins.
(Data outputs)		O0 to O7, O8 to O14 are used differently in the WORD mode and the BYTE
		mode.
		WORD mode (4M-word by 16-bit)
		The lower 15 bits of 16 bits data outputs to O0 to O14.
		(The most significant bit (O15) combined to A–1.)
		BYTE mode (8M-word by 8-bit)
		8 bits data outputs to O0 to O7 and also O8 to O14 are high impedance.
O15, A–1	Output, Input	O15, A-1 are used differently in the WORD mode and the BYTE mode.
(Data output 15,		WORD mode (4M-word by 16-bit)
LSB Address input)		The most significant output data bus (O15).
		BYTE mode (8M-word by 8-bit)
		The least significant address bus (A-1).
/CE	Input	Chip activating signal.
(Chip Enable)		When the OE is active, output states are following.
		High level: High-Z
		Low level : Data out
/OE or OE or DC	Input	Output enable signal. The active level of OE is mask option. The active level of
(Output Enable, Don't Care)		OE can be selected from high active, low active and Don't care at order.
Vcc	_	Supply voltage
GND	-	Ground
NC	-	Not internally connected (The signal can be connected).

Data Sheet M16084EJ4V0DS 5

Block Diagram





Mask Option

The active levels of output enable pin (/OE or OE or DC) are mask programmable and optional, and can be selected from among "0" "1" "×" shown in the table below.

Option	/OE or OE or DC	OE active level
0	/OE	L
1	OE	Н
×	DC	Don't care

Operation modes for each option are shown in the tables below.

Operation mode (Option: 0)

/CE	/OE	Mode	Output state
L	L	Active	Data out
	Н		High-Z
Н	H or L	Standby	High-Z

Operation mode (Option: 1)

/CE	OE	Mode	Output state
L	L	Active	High-Z
	Н		Data out
Н	H or L	Standby	High-Z

Operation mode (Option : x)

/CE	DC	Mode	Output state
L	H or L	Active	Data out
Н	H or L	Standby	High-Z

Remark L: Low level input

H: High level input



Electrical Specifications

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	Vcc		-0.3 to +4.6	V
Input voltage	Vı		-0.3 to Vcc + 0.3	V
Output voltage	Vo		-0.3 to Vcc + 0.3	V
Operating ambient temperature	TA		-10 to +70	°C
Storage temperature	T _{stg}		–65 to +150	°C

Caution Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Capacitance (TA = 25 °C)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input capacitance	Сі	f = 1 MHz			10	pF
Output capacitance	Со				12	pF

DC Characteristics (TA = -10 to +70 °C, Vcc = 2.7 to 3.6 V)

Parameter	Symbol		Test condition		MIN.	TYP.	MAX.	Unit
High level input voltage	VIH						Vcc + 0.3	V
Low level input voltage	VIL	Vcc = 3.0 V ± 0	0.3 V		-0.3		+0.5	V
		Vcc = 3.3 V ± 0	0.3 V		-0.3		+0.8	
High level output voltage	Vон	Іон = –100 μА			2.4			V
Low level output voltage	Vol	IoL = 2.1 mA					0.4	V
Input leakage current	lu	V _I = 0 V to V _{CC}	V _I = 0 V to V _{CC}				+10	μΑ
Output leakage current	ILO	Vo = 0 V to Vc	c, Chip deselected		-10		+10	μΑ
Power supply current	Icc1	/CE = VIL	V cc = 3.0 $V \pm 0.3 V$	TSOP (I)			40	mA
		(Active mode),		SOP			35	
		Io = 0 mA	$Vcc = 3.3 V \pm 0.3 V$	TSOP (I)			55	
				SOP			50	
Standby current	Іссз	/CE = Vcc - 0.2	2 V (Standby mode)				30	μΑ



AC Characteristics (TA = -10 to +70 °C, Vcc = 2.7 to 3.6 V)

Parameter	Symbol	Test condition	Vcc =	= 3.0 V ±	0.3 V	Vcc =	= 3.3 V ±	0.3 V	Unit
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Address access time	tacc	TSOP (I)			100			90	ns
		SOP			120			100	
Address skew time	tskew	Note			10			10	ns
Chip enable access time	t ce	TSOP (I)			100			90	ns
		SOP			120			100	
Output enable access time	t oe				25			25	ns
Output hold time	t он		0			0			ns
Output disable time	t DF		0		25	0		25	ns
WORD, /BYTE access time	twв	TSOP (I)			100			90	ns
		SOP			120			100	

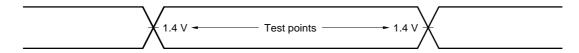
- **★ Note** tskew indicates the following three types of time depending on the condition.
 - 1) When switching /CE from high level to low level, tskew is the time from the /CE low level input point until the next address is determined.
 - 2) When switching /CE from low level to high level, tskew is the time from the address change start point to the /CE high level input point.
 - 3) When /CE is fixed to low level, tskew is the time from the address change start point until the next address is determined.

Since specs are defined for tskew only when /CE is active, tskew is not subject to limitations when /CE is switched from high level to low level following address determination, or when the address is changed after /CE is switched from low level to high level.

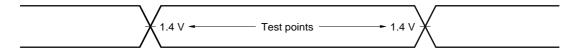
Remark top is the time from inactivation of Chip Enable input (/CE) or Output Enable input (/OE or OE) to high impedance state output.

AC Test Conditions

Input waveform (Rise / Fall Time ≤ 5 ns)



Output waveform



Output load

1 TTL + 100 pF

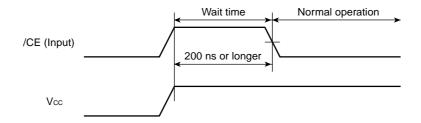


★ Cautions on power application

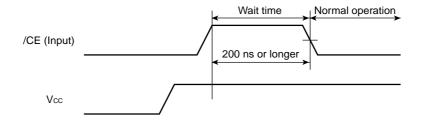
To ensure normal operation, always apply power using /CE following the procedure shown below.

- 1) Input a high level to /CE during and after power application.
- 2) Hold the high level input to /CE for 200 ns or longer (wait time).
- 3) Start normal operation after the wait time has elapsed.

Power Application Timing Chart 1 (When /CE is made high at power application)



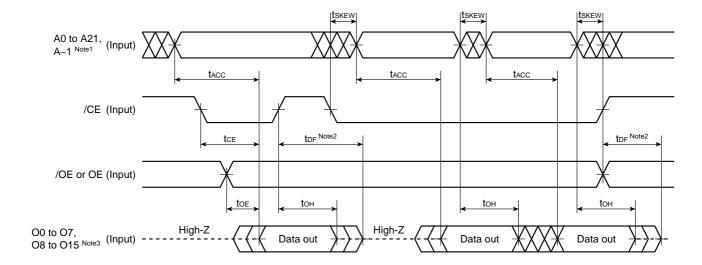
Power Application Timing Chart 2 (When /CE is made high after power application)



Caution Other signals can be either high or low during the wait time.

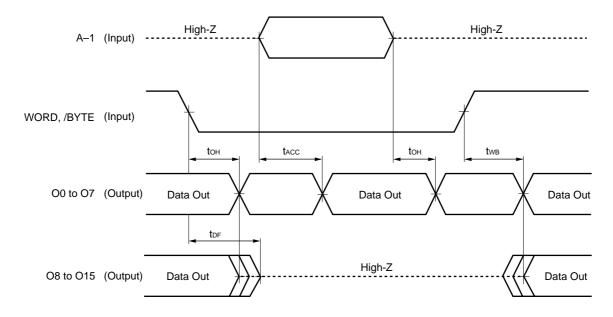


★ Read Cycle Timing Chart



- Notes 1. During WORD mode, A-1 is O15.
 - 2. top is the time from inactivation of Chip Enable input (/CE) or Output Enable input (/OE or OE) to high impedance state output.
 - 3. During BYTE mode, O8 to O14 are high impedance and O15 is A-1.

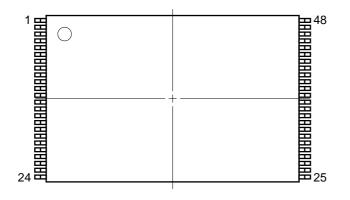
WORD, /BYTE Switch Timing Chart

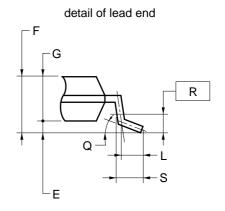


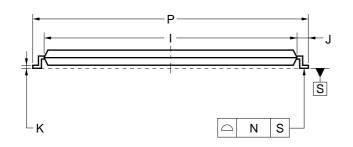
Remark Chip Enable (/CE) and Output Enable (/OE or OE): Active.

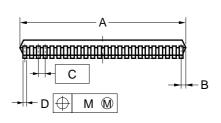
Package Drawings

48-PIN PLASTIC TSOP(I) (12x18)









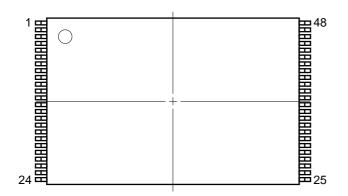
NOTES

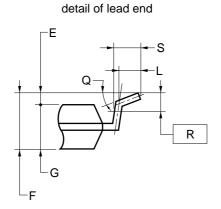
- 1. Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.
- 2. "A" excludes mold flash. (Includes mold flash : 12.4 mm MAX.)

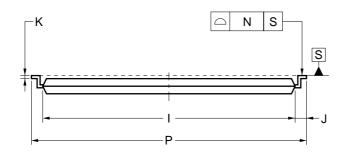
ITEM	MILLIMETERS		
Α	12.0±0.1		
В	0.45 MAX.		
С	0.5 (T.P.)		
D	0.22±0.05		
Е	0.1±0.05		
F	1.2 MAX.		
G	1.0±0.05		
I	16.4±0.1		
J	0.8±0.2		
K	0.145±0.05		
L	0.5		
М	0.10		
N	0.10		
Р	18.0±0.2		
Q	3°+5°		
R	0.25		
S	0.60±0.15		

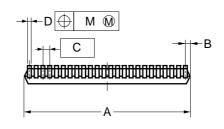
S48GY-50-MJH1-1

48-PIN PLASTIC TSOP(I) (12x18)









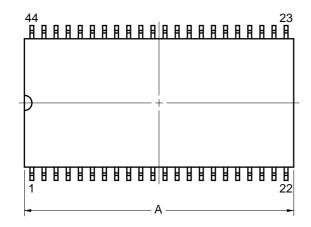
NOTES

- 1. Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.
- 2. "A" excludes mold flash. (Includes mold flash: 12.4 mm MAX.)

ITEM	MILLIMETERS		
Α	12.0±0.1		
В	0.45 MAX.		
С	0.5 (T.P.)		
D	0.22±0.05		
Е	0.1±0.05		
F	1.2 MAX.		
G	1.0±0.05		
I	16.4±0.1		
J	0.8±0.2		
K	0.145±0.05		
L	0.5		
М	0.10		
N	0.10		
Р	18.0±0.2		
Q	3°+5°		
R	0.25		
S	0.60±0.15		

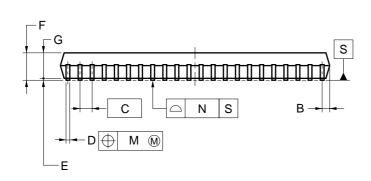
S48GY-50-MKH1-1

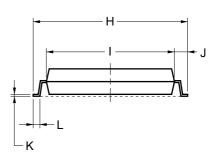
44-PIN PLASTIC SOP (15.24 mm (600))



detail of lead end







NOTE

Each lead centerline is located within 0.12 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS		
Α	27.83 ^{+0.4} _{-0.05}		
В	0.78 MAX.		
С	1.27 (T.P.)		
D	$0.42^{+0.08}_{-0.07}$		
E	0.15±0.1		
F	3.0 MAX.		
G	2.7±0.05		
Н	16.04±0.3		
1	13.24±0.1		
J	1.4±0.2		
K	$0.22^{+0.08}_{-0.07}$		
L	0.8±0.2		
М	0.12		
N	0.10		
Р	3°+7°		
	D446V F0 0004		

P44GX-50-600A-4



Recommended Soldering Conditions

Please consult with our sales offices for soldering conditions of the μ PD23C64000JL.

Types of Surface Mount Device

 μ PD23C64000JLGY-xxx-MJH : 48-pin PLASTIC TSOP (I) (12 \times 18) (Normal bent) μ PD23C64000JLGY-xxx-MKH : 48-pin PLASTIC TSOP (I) (12 \times 18) (Reverse bent)

 μ PD23C64000JLGX-xxx : 44-pin PLASTIC SOP (15.24 mm (600))



Revision History

Edition/	Page		Type of	Location	Description
Date	This	Previous	revision		(Previous edition \rightarrow This edition)
	edition	edition			
4th edition/	p.9	p.9	Addition	AC Characteristics	Address skew time (tskew)
Feb. 2003					Note
	p.10	_	Addition		Cautions on power application
	p.11	p.10	Modification		Read Cycle Timing Chart

 μ PD23C64000JL



[MEMO]

NEC μ PD23C64000JL

[MEMO]

NOTES FOR CMOS DEVICES

1 PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

(2) HANDLING OF THE APPLIED WAVEFORM OF INPUT PINS AND THE UNUSED INPUT PINS FOR CMOS

Note:

Input levels of CMOS devices must be fixed. CMOS devices behave differently than Bipolar or NMOS devices. If the input of a CMOS device stays in an area that is between VIL (MAX.) and VIH (MIN.) due to the effects of noise or some other irregularity, malfunction may result. Therefore, not only the input waveform is fixed, but also the waveform changes, it is important to use the CMOS device under AC test conditions. For unused input pins in particular, CMOS devices should not be operated in a state where nothing is connected, so input levels of CMOS devices must be fixed to high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

(3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

These commodities, technology or software, must be exported in accordance with the export administration regulations of the exporting country. Diversion contrary to the law of that country is prohibited.

- The information in this document is current as of February, 2003. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets or data books, etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without the prior
 written consent of NEC Electronics. NEC Electronics assumes no responsibility for any errors that may
 appear in this document.
- NEC Electronics does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC Electronics products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Electronics or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of a customer's equipment shall be done under the full responsibility of the customer. NEC Electronics assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC Electronics endeavors to enhance the quality, reliability and safety of NEC Electronics products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize risks of damage to property or injury (including death) to persons arising from defects in NEC Electronics products, customers must incorporate sufficient safety measures in their design, such as redundancy, fire-containment and anti-failure features.
- NEC Electronics products are classified into the following three quality grades: "Standard", "Special" and "Specific".

The "Specific" quality grade applies only to NEC Electronics products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.

- "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.
- "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).
- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).